DESCRIPTION

The fundamental of SP6015 synchronous rectifier (SR) driver IC is based on our U.S. patented methods that utilize the principle of "prediction" logic circuit. The IC deliberates previous cycle timing to linear control the SR in present cycle by "predictive" algorithm that makes adjustments to the turn-off time, in order to achieve maximum efficiency and avoid cross-conduction at the same time. Specially, SP6015 is designed for LLC applications, and variable switching frequency system.

The SP6015 is a dual fast turn-off intelligent controller to drive two N-CH power MOSFETs in LLC resonant converters for synchronous rectification.

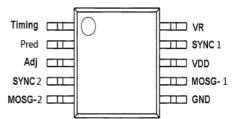
FEATURES

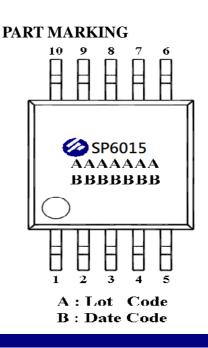
- Offers efficiency improvement over Schottky Diode.
- Low Standby Power to meet DOE Lot 6 Requirement.
- Dual gate driver for N-channel MOSFET
- Drives all level Power MOSFET.
- Prediction gate timing control.
- Minimum MOSFET body diode conduction.
- Operating frequency up to 250 KHz.
- Synchronize to transformer secondary voltage waveform.
- Self detect DCM / CCM to enhance the performance under the variable switching frequency condition.

APPLICATIONS

- Storage area network power supplies
- Telecommunication converters
- Embedded systems
- Industrial & commercial systems using high current processors
- Power converters to meet Lot 6 requirement

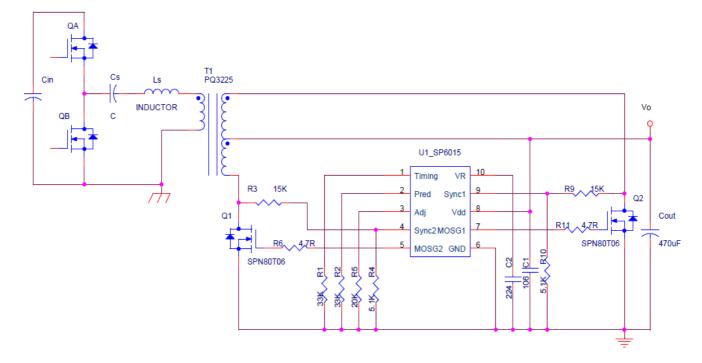
PIN CONFIGURATION (SSOP-10)







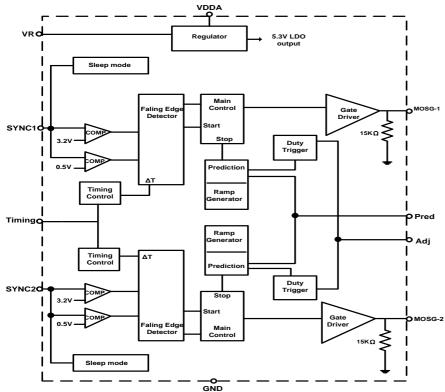
TYPICAL APPLCATION CIRCUIT



PIN DESCRIPTION

Pin	Symbol	Description	
1	Timing	Discontinuous current filter timing adjustment resistor connection.	
2	Pred	Capacitor to store previous cycle timing for SR MOSFET.	
3	Adj	Trigger point adjustment for Dynamic state.	
4	SYNC-2	Synchronized signal from the V _{DS} of SR MOSFET.	
5	MOSG-2	Catch MOSFET gate drive.	
6	GND	Ground connection.	
7	MOSG-1	Catch MOSFET gate drive.	
8	Vdd	DC supply voltage.	
9	SYNC-1	Synchronized signal from the V _{DS} of SR MOSFET.	
10	VR	Voltage Regulator.	

BLOCK DIAGRAM



ORDERING INFORMATION

Part Number	Package	Part Marking
SP6015S10RGB	SSOP-10	SP6015

* SP6015S10RGB : Tape Reel ; Pb – Free ; Halogen - Free

ABSOULTE MAXIMUM RATINGS (TA=25°C, unless otherwise specified.)

The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Paramete	Value	Unit
V _{dd}	DC Supply Voltage	17.5	V
I _{OUT}	Peak Source Current (Pulsed)	2.0	А
	Peak Sink Current (Pulsed)	2.0	А
P _D	Power Dissipation @ $T_A = 85^{\circ}C$ (*)	0.25	W
T _J	Operating Junction Temperature Range	-40 to125	°C
T _{STG}	Storage Temperature Range	-40 to 150	°C
T _{LEAD}	Lead Soldering Temperature for 5 sec.	260	°C

THERMAL RESISTANCE

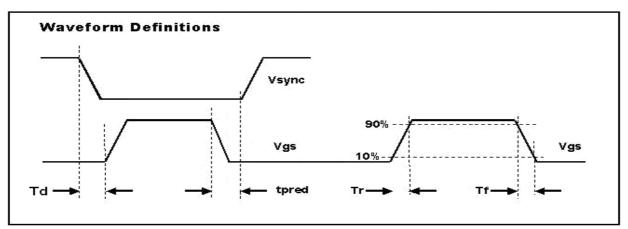
Symbol	Paramete	Value	Unit
Roja	Thermal Resistance Junction to Ambient (*)	130	°C/W

ELECTRICAL CHARACTERISTICS

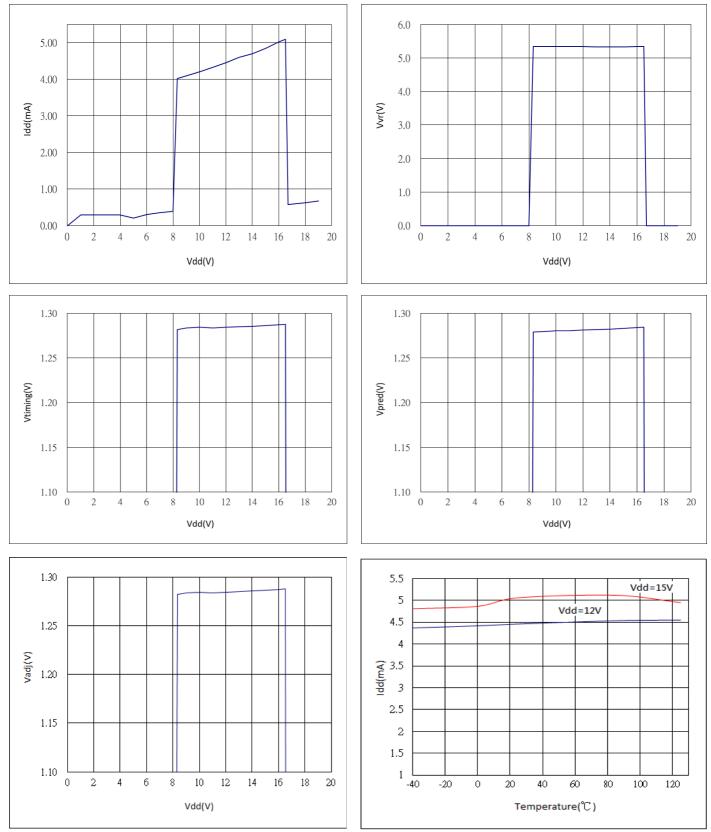
(T_A=25°C, V_{dd}=12V, Freq. =50 KHz, Duty Cycle=50%, unless otherwise specified.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
SUPPLY INP	UT					
Idd	Second and a second set	No load		4.5		mA
	Supply current	V _{SYNC} =0V, Vdd on (Sleep mode)		550		uA
Vdd	Supply voltage	Idd peak $< 2A$			16	V
Vdd on	Enable voltage		7.9	8.3	8.8	V
Vdd hysteresis	Enable voltage			0.8		v
Vovp	Over voltage protection		16	16.3	17	V
Vovp hystersis				0.46		V
SYNC REFE	ERENCE (SYNC)	L				
Vshth	SYNC high threshold			3.2		V
Vslth	SYNC low threshold			0.5		V
Vsync WK	SYNC wake-up voltage	Isync=3mA		4.6		V
Vsync	SYNC clamp voltage	Isync=3mA	Vdd+0.7			V
Isync	SYNC input current				3	mA
Voltage Regi	ulator REFERENCE (V)	R)				
VR	voltage		5.2	5.3	5.4	V
Ivr	VR Output Current				30	mA
ON TIME D	UTY SETUP (PIN 5,7)					
Ton-time		Frequency= 10KHz-20KHz, Duty=20%~50%		26	36	uS
MOSFET G.	ATE DRIVER (MOSG-C					
Voh	Output high voltage	Io =-200mA	10.5	11.0		V
Vol	Output low voltage	Io=200mA		0.3	0.8	V
Td	Propagation delay	No load		280	380	nS
Tpred		Rtiming=33KΩ		1000		nS
Tr	Rise time	Load = 1nF(*)		12		nS
Tf	Fall time	Load = 1nF(*)		10		nS
Dynamic Pro	otect				L	
Dt	Dynamic variable	Pin3 , 51KΩ		1		uS
	MOSG-C on time	PWM adjusts time > Dt	- 1	0.9	1	uS

(*) Tr & Tf are measured among 10% and 90% of starting and final voltage.

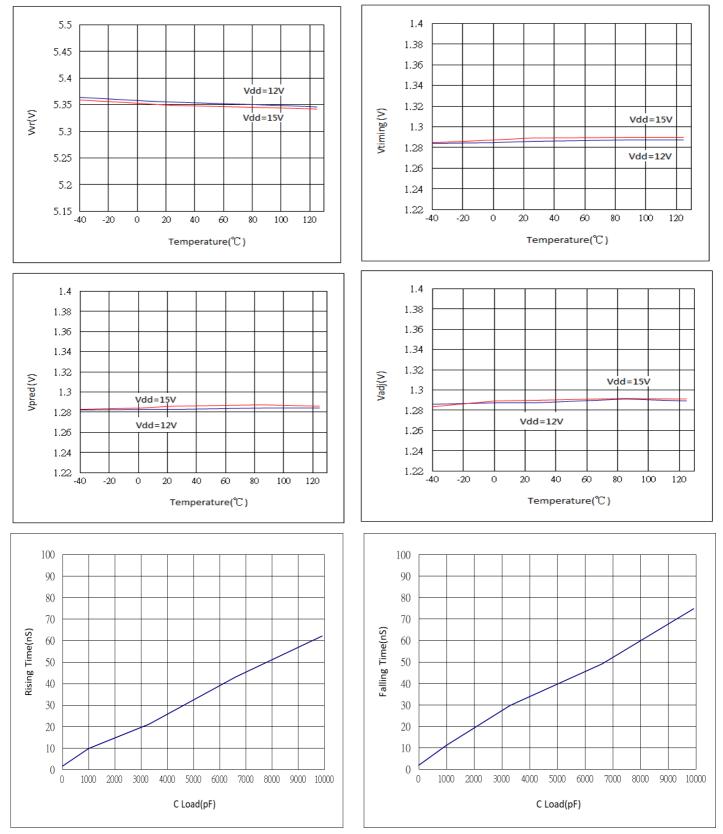


PERFORMANCE CHARACTERISTICS (T_A=25°C, unless otherwise specified.)



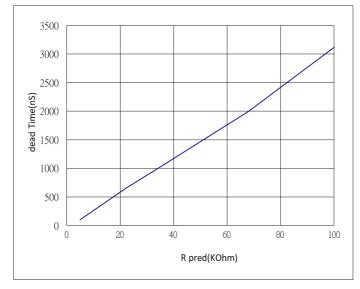
2018/6/15 Ver 2

PERFORMANCE CHARACTERISTICS (T_A=25°C, unless otherwise specified.)



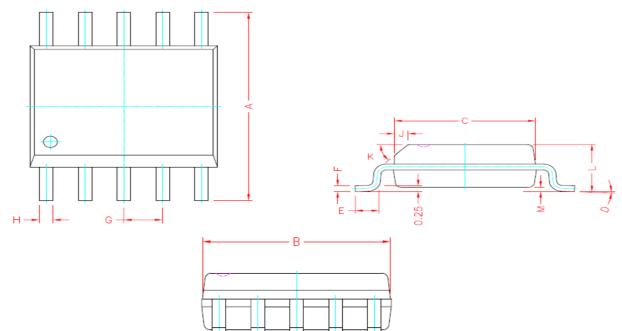
2018/6/15 **Ver 2**

PERFORMANCE CHARACTERISTICS (T_A=25°C, unless otherwise specified.)





SSOP- 10 PACKAGE OUTLINE



	DIMENSIONS		
REF.	Millimeters		
	Min.	Max.	
А	5.80	6.20	
В	4.80	5.00	
С	3.80	4.00	
D	0°	8°	
E	0.40	0.90	
F	0.19	0.25	
М	0.10	0.25	
н	0.30	0.44	
L	1.35	1.75	
J	0.375 REF.		
K	45°		
G	1.00 TYP.		



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